NSN 5961-01-117-8265

Transistor - Page 1 of 1

A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-117-8265 **Inclosure Material:** Metal **Overall Length:** 0.405 inches **End Application:** An/apx-76b **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 65.0 collector to base voltage/static/emitter open and 65.0 collector to emitter reverse voltage, with base short-circuited to emitter and 3.5 emitter to base voltage, static, collector open **Power Rating Per Characteristic:** 160.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** External surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 pin and 2 flange Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: